# Astrometric Error Measurements using a dithered array of 40,000 stars

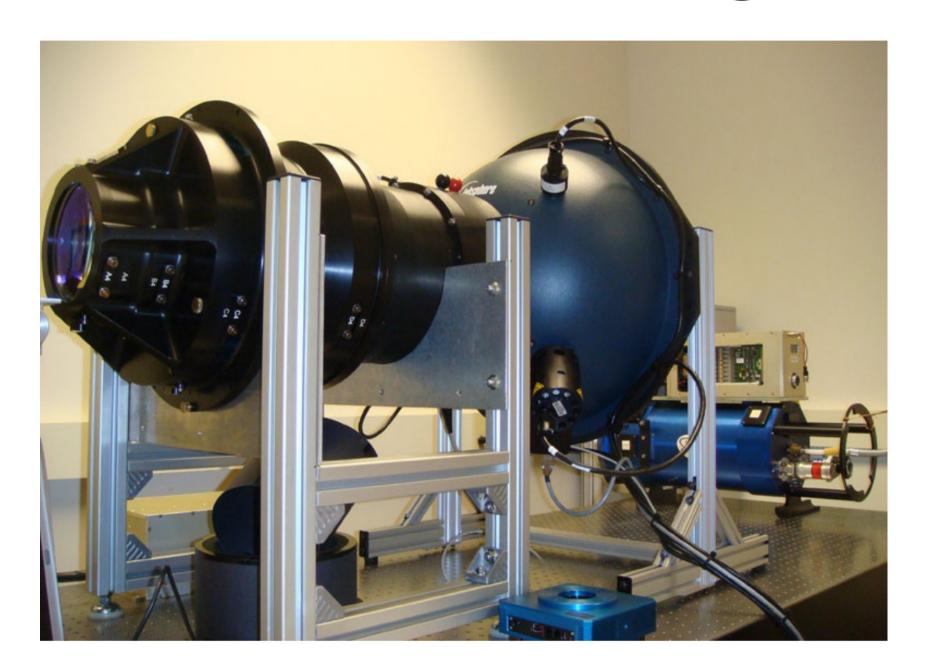
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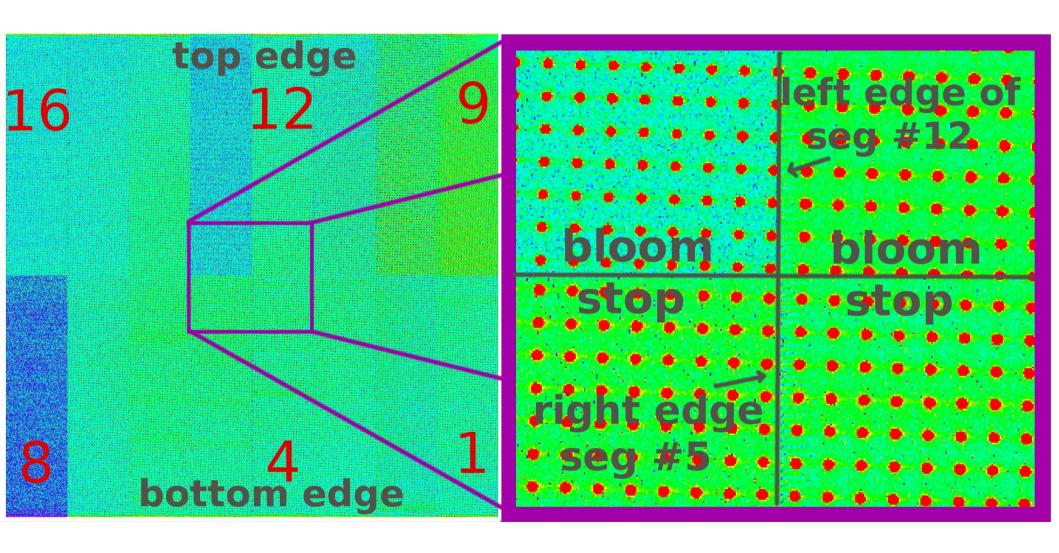
### **Outline**

- Our f/1 beam simulator lab, 40k pinhole array and dither method
- 2) Overview analysis method for CCD segments
- 3) Modeling of edge occultation effect
- 4) Astrometric residuals near edges of segments
- Modeling pixel boundary shift at edges and qualitative comparison to measurements

### LSST f/1 Beam Simulator @ UCD

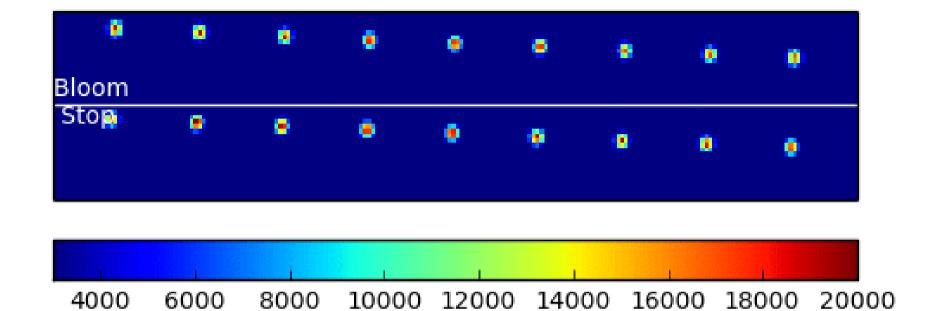


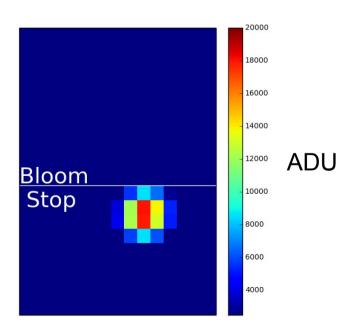
## STA 1920A layout & naming conventions



40,000 pinholes, 30 micron diameter, spaced 200 microns

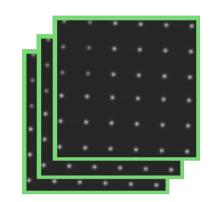
### Dither animations

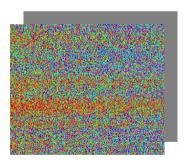




### Analysis pipeline (1)

- Acquire exposures:
  - 300 dithered images w/ X&Y sub-pix shifts
  - 6 illumination levels, max=1,000→60,000 e-
  - Only R filter so far
- Debias subsegment:
  - Create master bias from 250 bias frames
  - Use overscan to remove intermittent line noise
  - Subtract master bias (overscan subtracted)
     from sub-segment (also overscan subtracted)

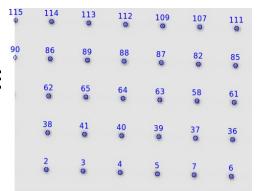


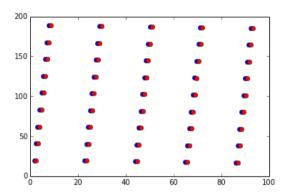


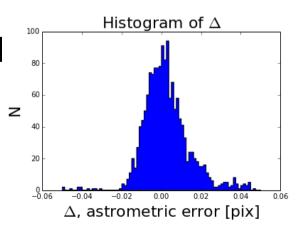
## Analysis pipeline (2)

- Identify ~2000 pinholes in each segment frame using SExtractor
  - Catalog created has precision X&Y centroids, fluxes, & shapes measured
- Use python to read in consecutive catalogs and compute median shift of all pinholes in X & Y
- Measure deviation, Δ, from median shift in region of interest (i.e. edges, bloom stops)
  - Median shift known to better than .05 pixel

CPU time per 300 images: ~100min

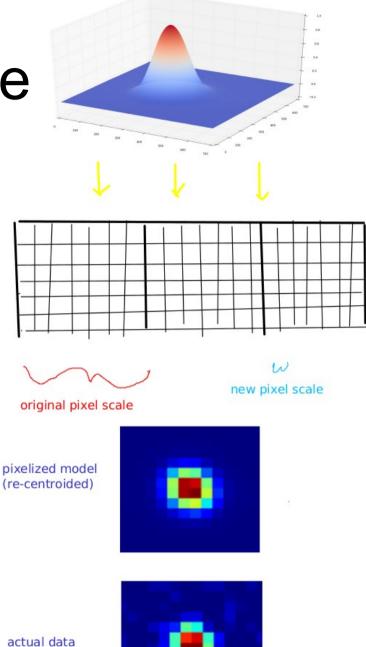




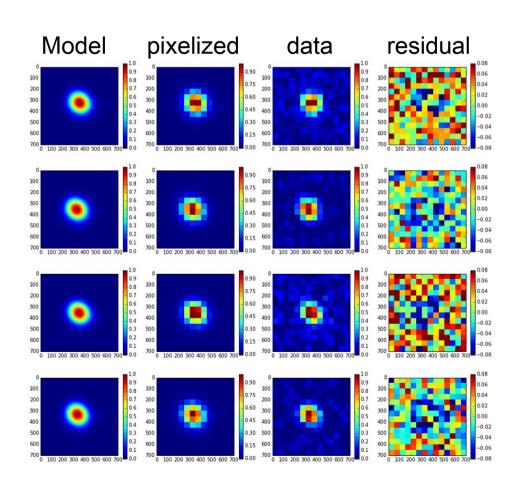


# How to model a pixelized pinhole image

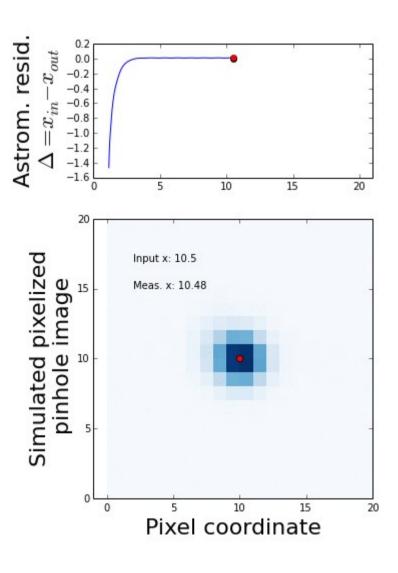
(Necessary for modeling the occultation effect at each edge)



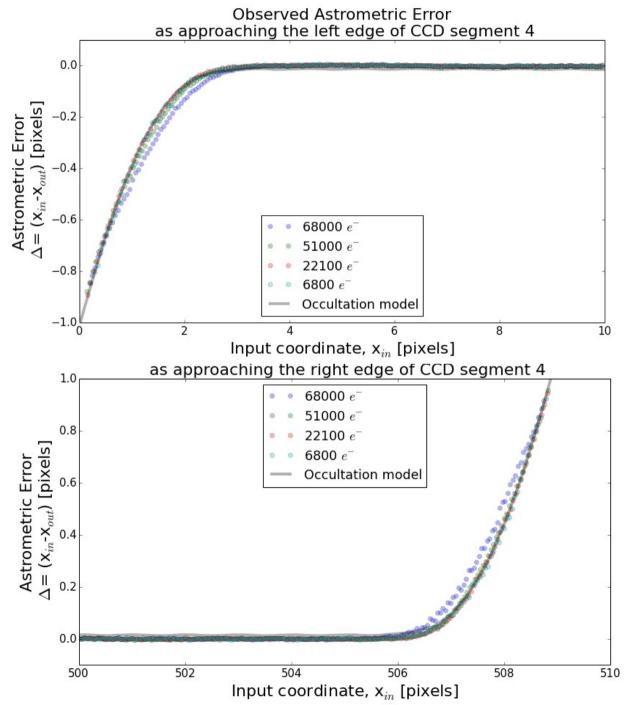
subpixel grid



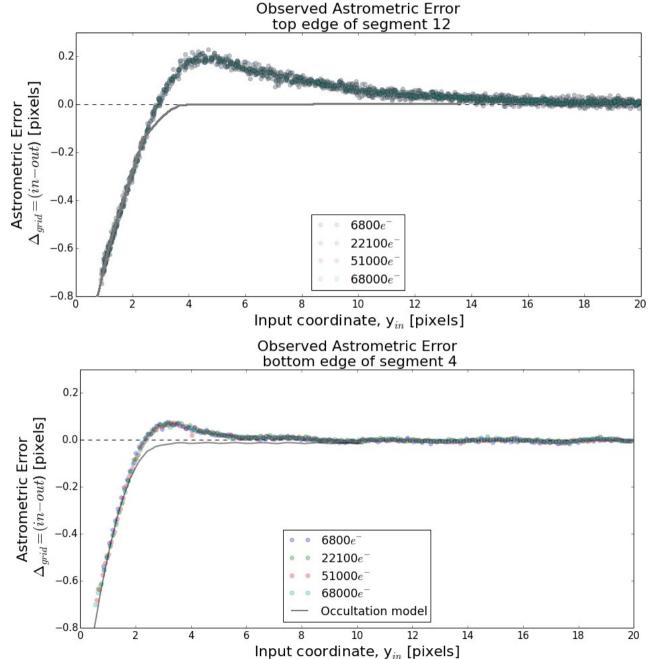
## Animation of model pixelized PSF approaching an edge



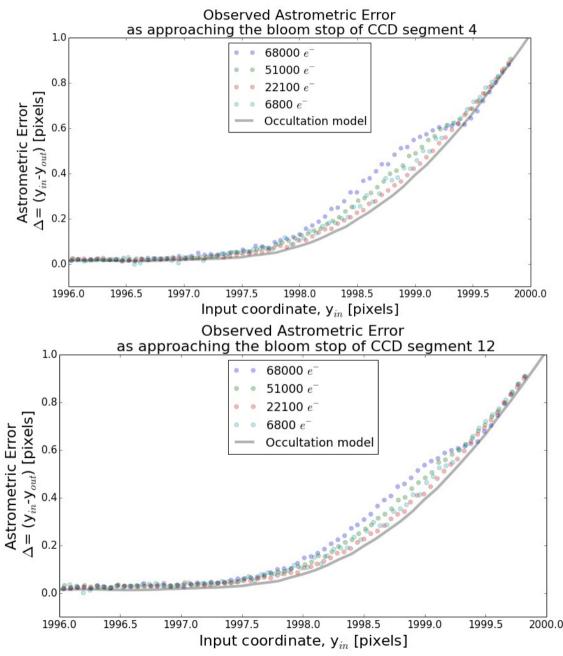
## @ left & right edge of seg # 4



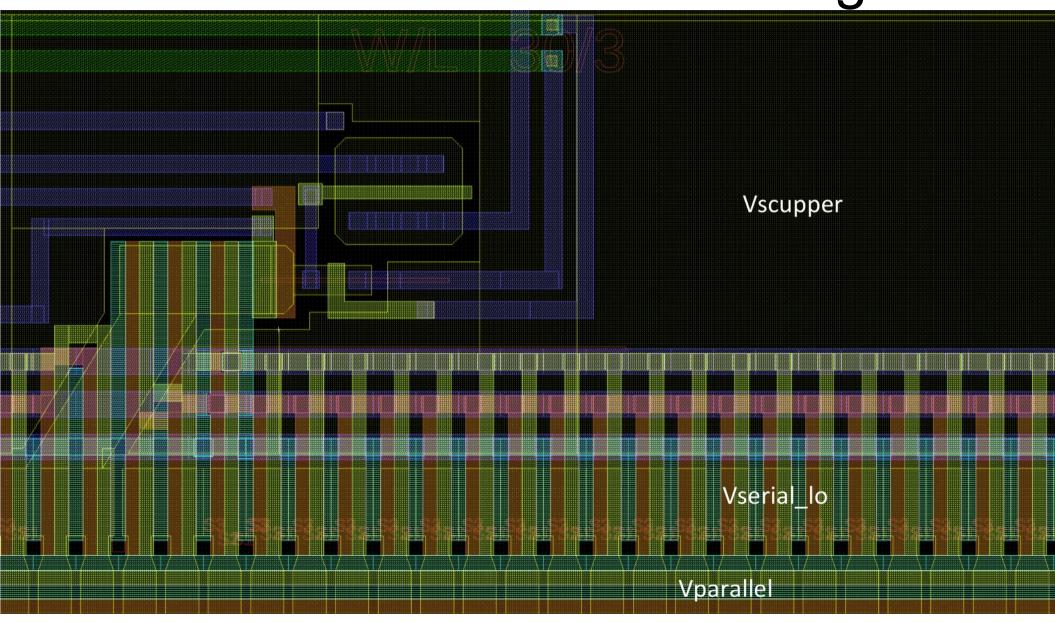
### @ top, bottom of CCD (seg # 12, 4)



# @ bloom stop approached from below (4) and above (12)



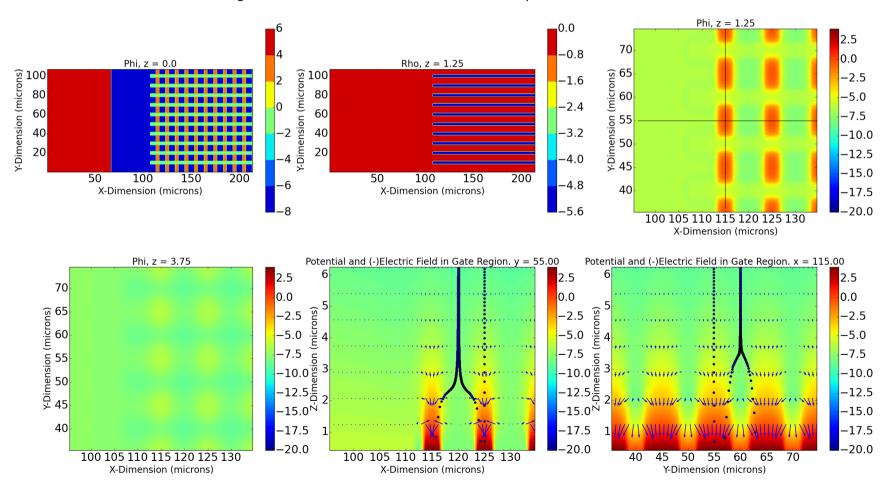
### CAD masks near serial edge



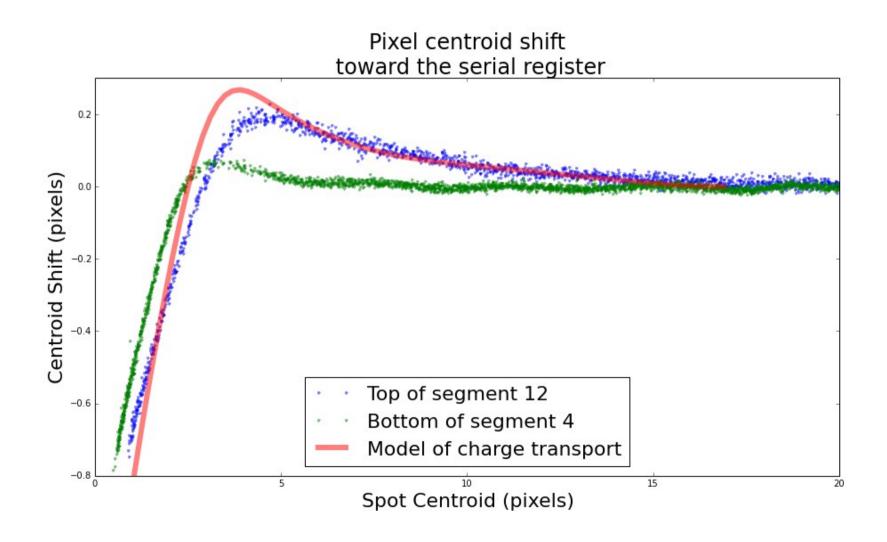
### Potential map near serial edge

Use **toy Poisson model** of scupper, serial, and parallel potentials to predict charge deflection → calculated approx. pixel boundaries shift near serial reg.

CCD Charge Collection. Grid = 256\*128\*128. Elapsed Time = 42.0 seconds.



## Toy model of pixel shift near serial has similar shape & amplitude



#### Conclusions

- CCDs are not perfect detectors, but are quirky and need to be understood for precision cosmology
- Optimizing CCD performance requires rigorous characterization
- Future work on characterization:
  - Changing wavelength/filter
  - Backside bias
  - Variable sky level
  - Pinhole size (3 micron mask ready to use)
  - Pinhole shape
- Questions, comments, ideas!